

ME2188

High Efficiency ,synchronous PFM step-up DC-DC converter

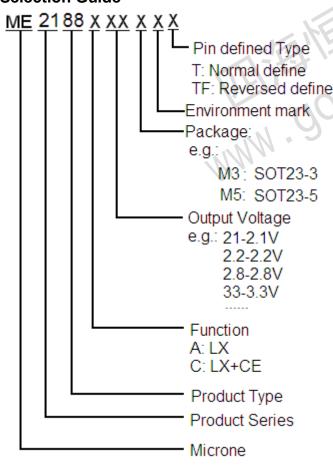
General Description

ME2188 Series is a PFM Step-up DC/DC converter IC with low supply current by CMOS process. High frequency noise that occurs during switching is reduced by using advanced circuit designed, output voltage is programmable in 0.1V steps between 1.8V~5.0V and maximum frequency is 350KHz(TYP.). A low ripple, high efficiency step-up DC/DC converter can be constructed of ME2188Xxx with only two external components. ME2188Xxx is suitable for use with battery-powered instruments with low noise and low supply current.

Features

- High efficiency: 95%
- Maximum frequency: 350KHz
- Low Quiescent Current: 15µA
- Input Voltage: 0.9V~5.0V
- Output Voltage Range: 1.8V to 5.0V
- High Accuracy:± 2%
- Low ripple and Low noise
- Package: SOT23-3, SOT23-5

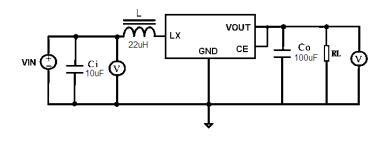
Selection Guide



Typical Application

- Power source for battery-powered equipment
- Power source for Wireless mouse,toys,
 Cameras, VCRs, PDAs, MP3, and Led lighting etc.

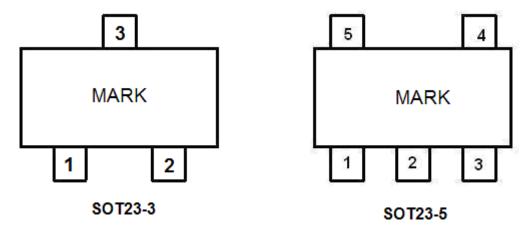
Typical Application Circuit



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Pin Configuration



Pin Assignment

TYPE	POSTFIX	PACKAGE	SWITCHING TRANSISTOR	CE FUNCTION	FEATURES
ME2188Axx	М3	SOT23-3	Build in Transistor	No	Lx
ME2188Cxx	M5	SOT23-5	Build in Transistor	Yes	LX+CE

ME2188AXX

Pin Number	Pin Name	Description
SOT23-3	Fill Name	Description
1	GND	Ground
3	VOUT	Voltage output
2	LX	Switch pin

ME2188CXX

PIN Number	Pin Name	Function
SOT23-5	Pili Naille	Fullction
1	CE	Chip enable
2	VOUT	Output voltage monitor, IC internal power supply
3	NC	NC
4	GND	Ground
5	LX	Switch

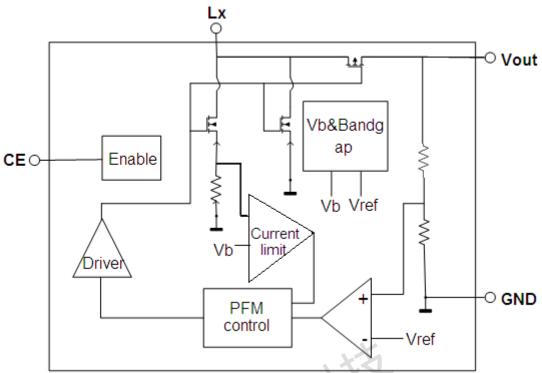
Absolute Maximum Ratings

Parameter	Symbol	Ratings	Units	
Supply Voltage	V _{MAX}	8	V	
LX pin current	ILXmax	1000	mA	
	SOT23	P _D	300	mW
Continuous Total Power Dissipation	SOT89	P _D	500	mW
	TO92	P _D	500	mW
Operating Temperature Rai	T _{OPR}	-20~+85	$^{\circ}$	
Storage Temperature Ran	T _{STG}	-40~125	${\mathbb C}$	
ESD	V _{ESD}	2000	V	

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Block Diagram



Electrical Characteristics

 T_A =25 0 C, V_{in} = $V_{OUT} \times 0.6$ V, L=22 μ H, C_{IN} =10 μ F, C_{OUT} =100 μ F, unless otherwise noted.

ME2188Axx/Cxx

Symbol	Parameter	Test Conditions	MIN	TYP	MAX	UNIT
V _{OUT}	Output Voltage	00,	$V_{OUT} \times 0.98$	V _{OUT}	V _{OUT} × 1.02	V
V_{IN}	Supply Voltage	M.	0.9	-	5	V
V _{START}	Start voltage	Iload=1mA, Vin: 0→2V	-	-	0.95	V
Vhold	Hold voltage	Iload=1mA, Vin: 2→0V	0.5	-	-	V
Fosc	oscillation frequency		-	350	-	KHz
η	Efficiency		-	90	95	%
llimit	Current limit		800	1000	1200	mA
I _{IN}	Quiescent Current		-	15	-	μA

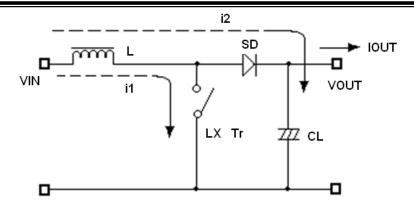
Note: 1. Inductor: $22\mu H (r<0.5\Omega)$ 2. Capacitor: Tantalum type

Operation Description

ME2188 step-up DC/DC converter charges energy in the inductor when Lx Transistor is on, and discharges the energy with the addition of the energy from input power source thereto, so that a higher output voltage than the input voltage is obtained. Following is the operation diagram.

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Switching DC/DC Step up Converter operating process

PCB Layout:

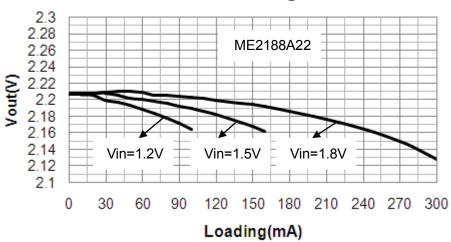
- ♦ Set external components as close as possible to the IC and minimize the connection between the components and the IC. In particular, when an external component is connected to VOUT Pin, make minimum connection with the capacitor.
- → Make Vss pin sufficient grounding, otherwise, the zero level within IC will varied with the switching current. This may result in unstable operation of IC.

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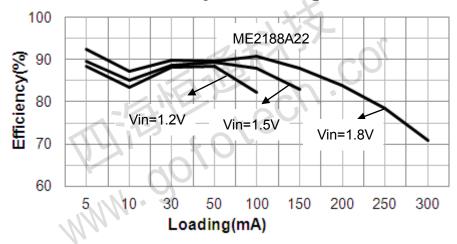


Type Characteristics

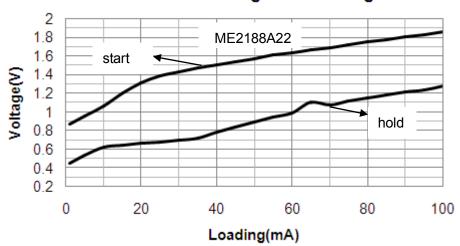




Efficiency vs. Loading

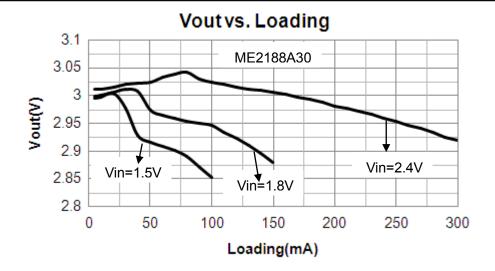


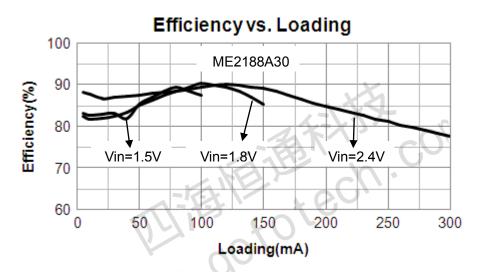
Start and Hold Voltage vs. Loading

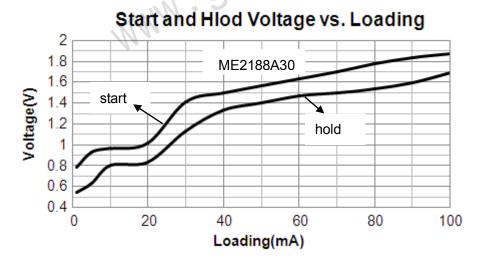


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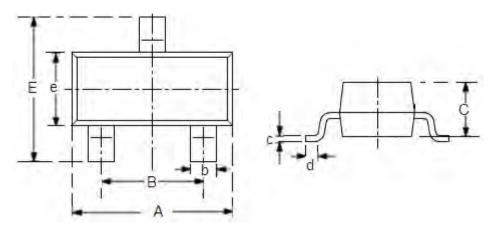


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一级代理:深圳市四海恒通科技有限公司 Tel: 0755-8398 3377 / 135 9011 2223 http://www.gofotech.com

Packaging Information Packaging Type: SOT23-3

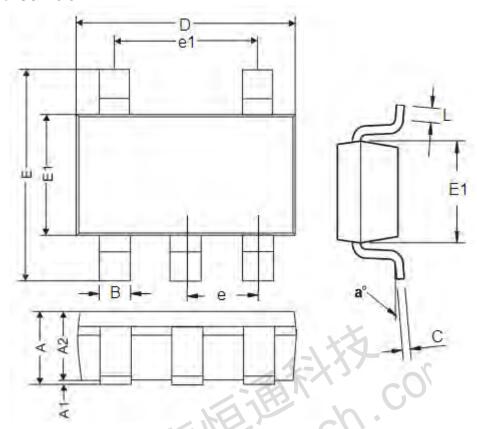


DIM	Millim	eters	Inches		
	Min	Max	Min	Max	
А	2.7	3.1	0.1063	0.122	
В	1.7	2.1	0.0669	0.0827	
b	0.35	0.5	0.0138	0.0197	
С	1.0	1.2	0.0394	0.0472	
С	0.1	0.25	0.0039	0.0098	
d	0.2	\\ \ - \{ C	0.0079	1	
Е	2.6	3.0	0.1023	0.1181	
е	1.5	1.8	0.059	0.0708	

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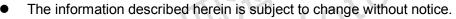
Packaging Type: SOT23-5



DIM	Millim	neters	Inches		
	Min	Max	Min	Max	
А	0.9	1.45	0.0354	0.0570	
A1	0	0.15	0	0.0059	
A2	0.9	1.3	0.0354	0.0511	
В	0.2	0.5	0.0078	0.0196	
С	0.09	0.26	0.0035	0.0102	
D	2.7	3.10	0.1062	0.1220	
Е	2.2	3.2	0.0866	0.1181	
E1	1.30	1.80	0.0511	0.0708	
е	0.95REF		0.0374REF		
e1	1.90REF		0.0748REF		
L	0.10	0.60	0.0039	0.0236	
a ⁰	00	30 ⁰	00	30 ⁰	

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